

## GaAs pHEMT MMIC 1 WATT POWER AMPLIFIER, DC - 22 GHz

### Typical Applications

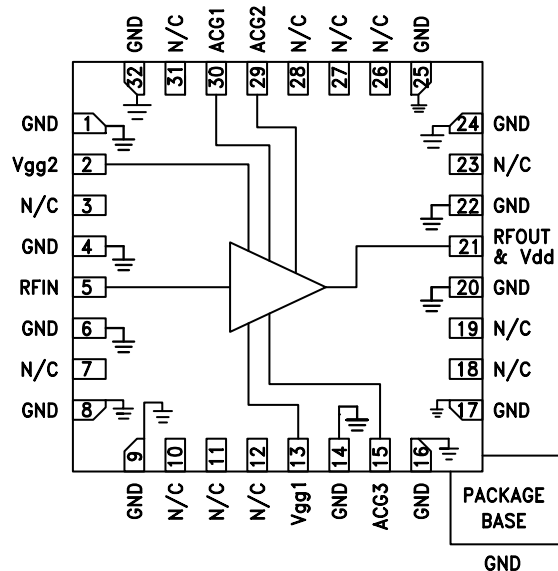
The HMC797APM5E is ideal for:

- Test Instrumentation
- Military & Space
- Fiber Optics

### Features

- High P1dB Output Power: +29 dBm
- High Psat Output Power: +31 dBm
- High Gain: 15 dB
- High Output IP3: +41 dBm
- Supply Voltage: +10 V @ 400 mA
- 50 Ohm Matched Input/Output
- 32 Lead 5x5 mm SMT Package: 25 mm<sup>2</sup>

### Functional Diagram



### General Description

The HMC797APM5E is a GaAs MMIC pHEMT Distributed Power Amplifier which operates between DC and 22 GHz. The amplifier provides 15 dB of gain, +29 dBm of output power at 1 dB gain compression, +31 dBm of saturated output power, and 25% PAE while requiring 400 mA from a +10 V supply. With up to +41 dBm of output IP3, the HMC797APM5E is ideal for high linearity applications in military and space as well as test equipment where high order modulations are used. This versatile PA exhibits a positive gain slope from 2 to 20 GHz making it ideal for EW, ECM, Radar and test equipment applications. The HMC797APM5E amplifier I/Os are internally matched to 50 Ohms facilitating integration into multi-chip-modules (MCMs), is packaged in a leadless QFN 5x5 mm surface mount package, and requires no external matching components.

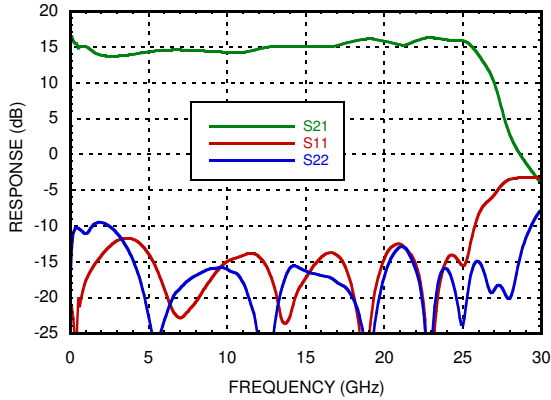
### Electrical Specifications, $T_A = +25^\circ\text{C}$ , $V_{dd} = +10\text{V}$ , $V_{gg2} = +3.5\text{V}$ , $I_{dd} = 400\text{mA}^*$

Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range	DC - 12			12 - 18			18 - 22			GHz
Gain	12.5	14.5		13	15		13	15.5		dB
Gain Flatness		±0.7			±0.5			±0.5		dB
Gain Variation Over Temperature		0.014			0.018			0.02		dB/°C
Input Return Loss		15			15			15		dB
Output Return Loss		13			15			13		dB
Output Power for 1 dB Compression (P1dB)	27	29		27	29		26	29		dBm
Saturated Output Power (Psat)		31			31			31		dBm
Output Third Order Intercept (IP3) *Measurement taken at Pout/Tone = + 18 dBm		42			41			41		dBm
Noise Figure		3.0			3.5			4		dB
Supply Current (Idd)		400			400			400		mA
Supply Voltage (Vdd)	8	10	11	8	10	11	8	10	11	V

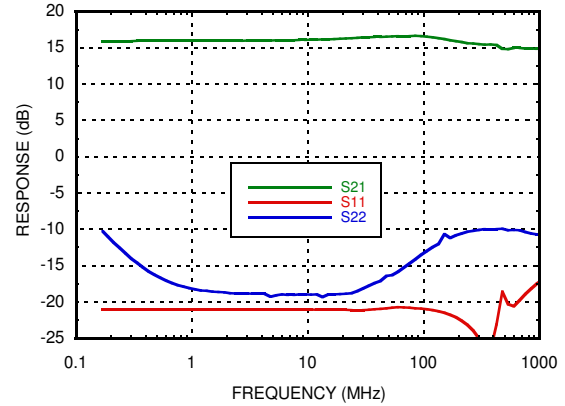
\* Adjust Vgg1 between -2 to 0 V to achieve Idd = 400 mA typical, Vgg1 = -0.55V Typical to achieve Idd = 400 mA.

**GaAs pHEMT MMIC  
1 WATT POWER AMPLIFIER, DC - 22 GHz**

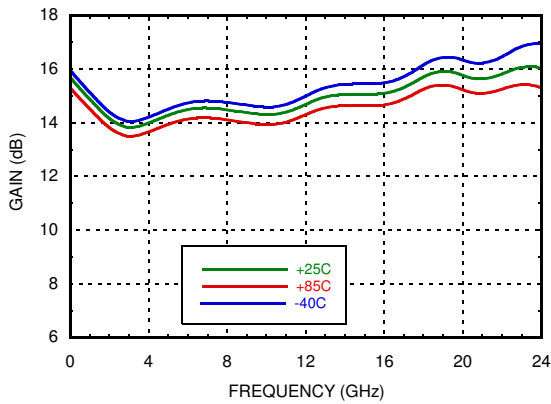
**Broadband Gain and Return Loss**



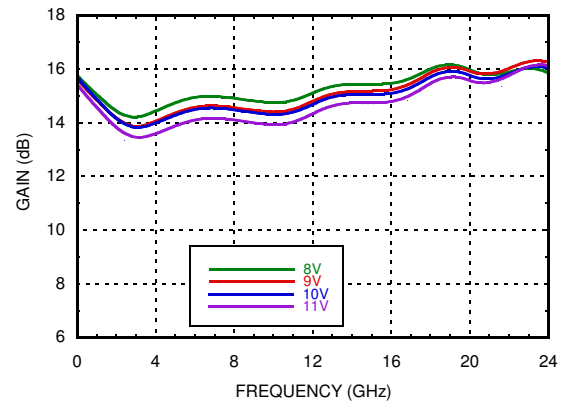
**Low Frequency Gain and Return Loss**



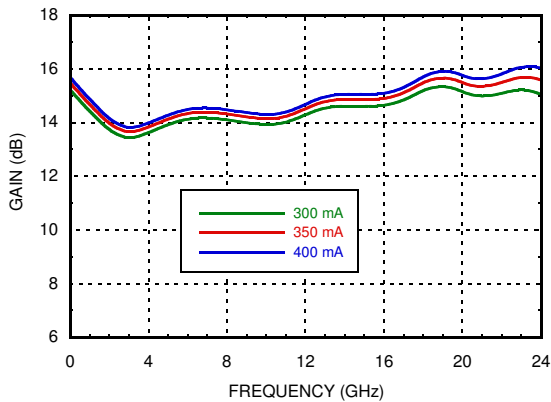
**Gain vs. Temperature**



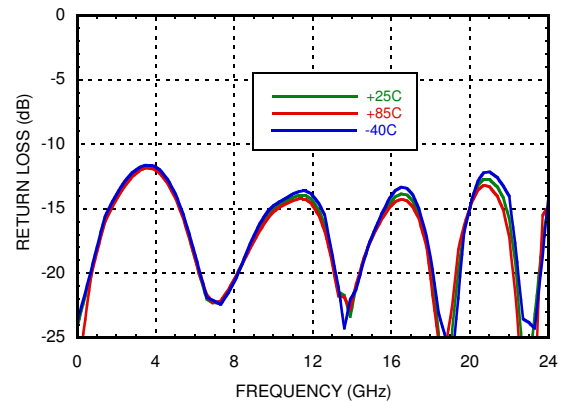
**Gain vs. Vdd**



**Gain vs. Idd**

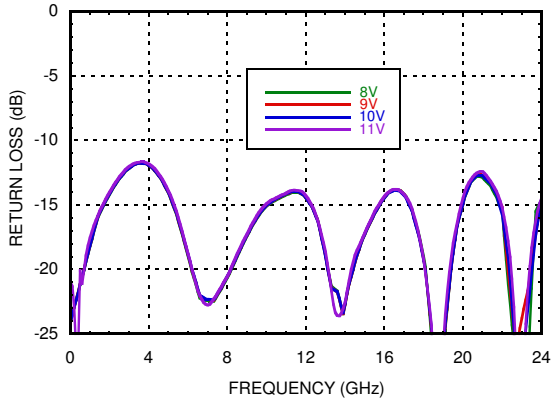


**Input Return Loss vs. Temperature**

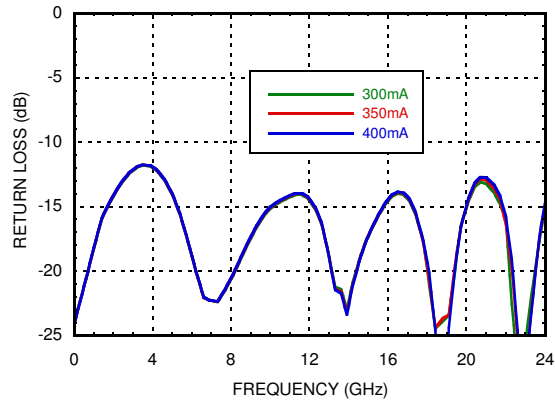


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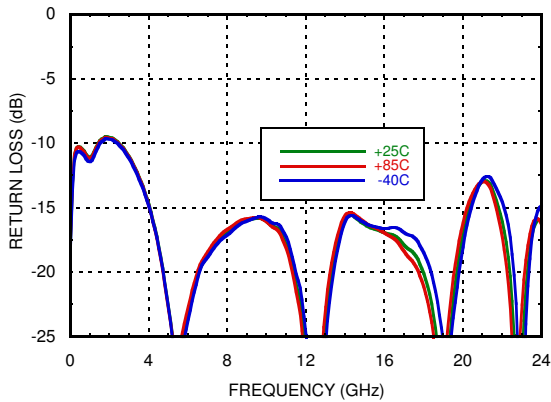
**Input Return Loss vs. Vdd**



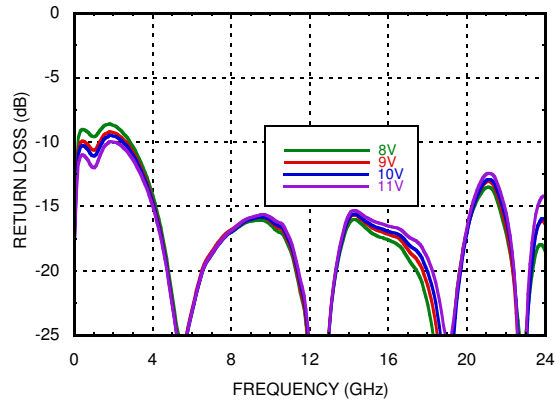
**Input Return Loss vs. Idd**



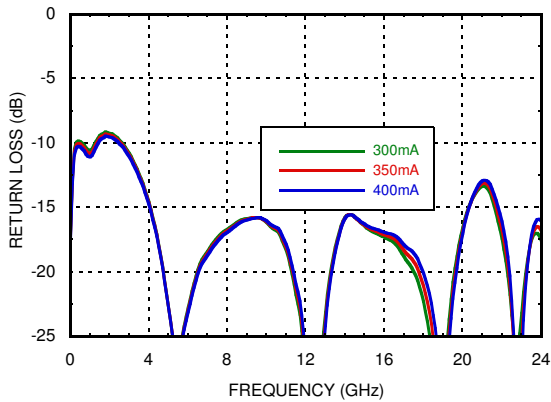
**Output Return Loss vs. Temperature**



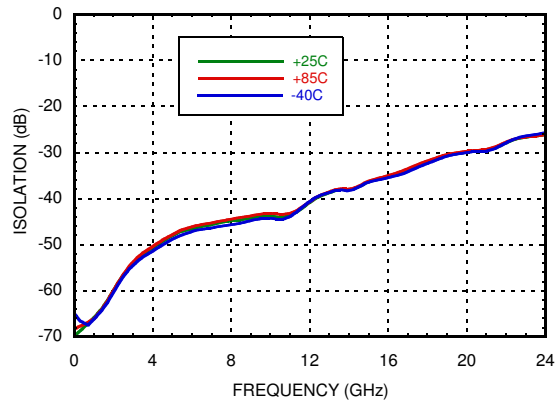
**Output Return Loss vs. Vdd**



**Output Return Loss vs. Idd**

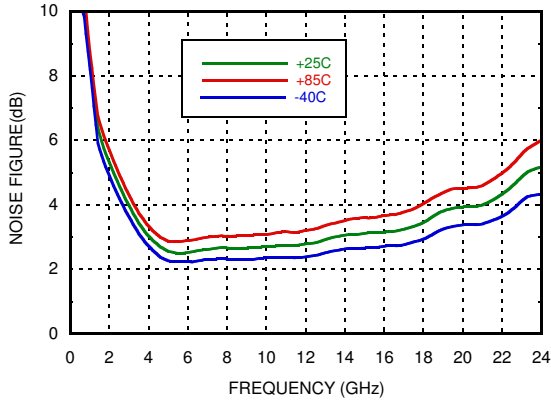


**Reverse Isolation vs. Temperature**

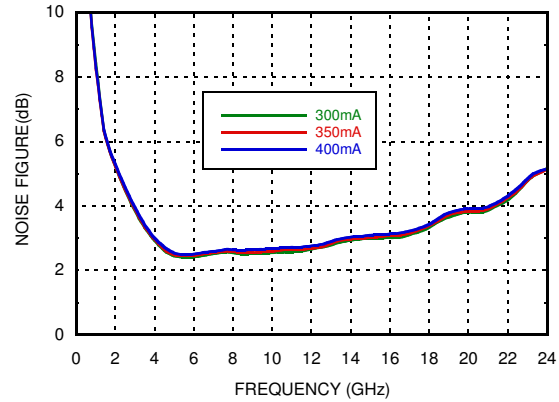


**GaAs pHEMT MMIC  
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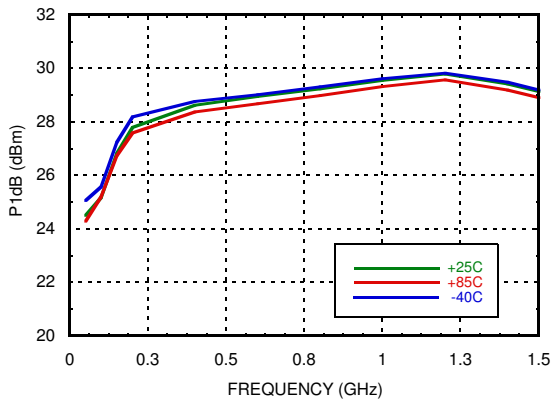
**Noise Figure vs. Temperature**



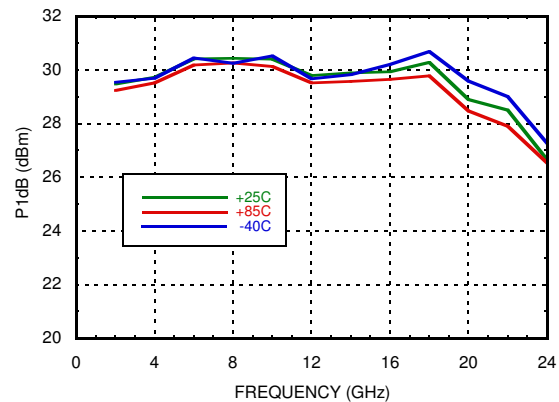
**Noise Figure vs. I<sub>dd</sub>**



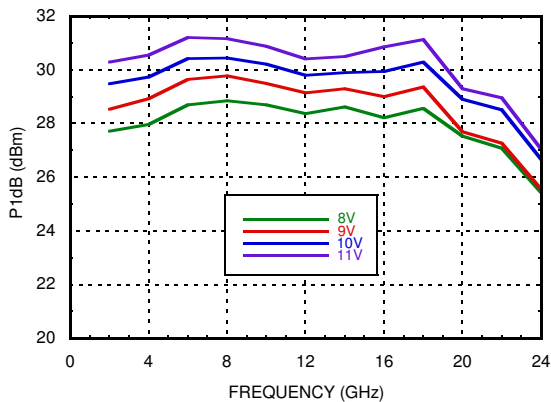
**Low Frequency P<sub>1dB</sub> vs. Temperature**



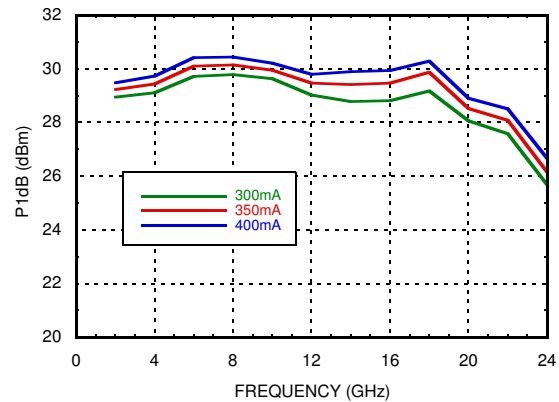
**P<sub>1dB</sub> vs. Temperature**



**P<sub>1dB</sub> vs. V<sub>dd</sub>**

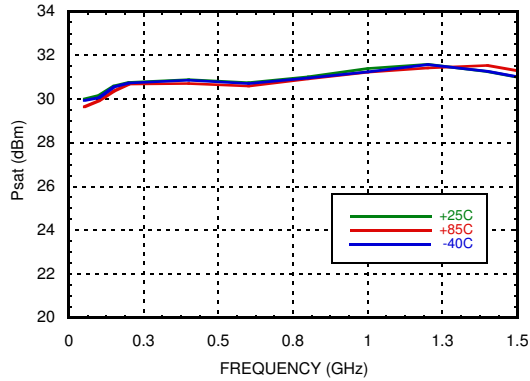


**P<sub>1dB</sub> vs. I<sub>dd</sub>**

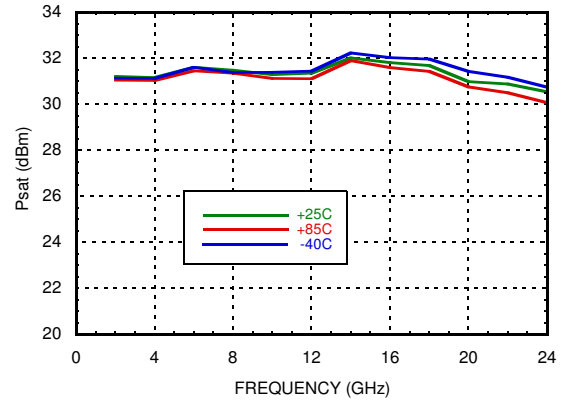


**GaAs pHEMT MMIC  
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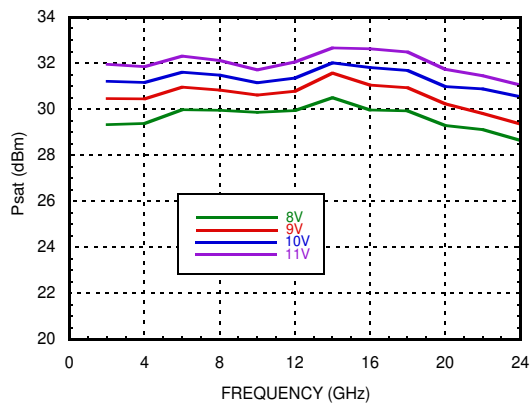
**Low Frequency Psat vs. Temperature**



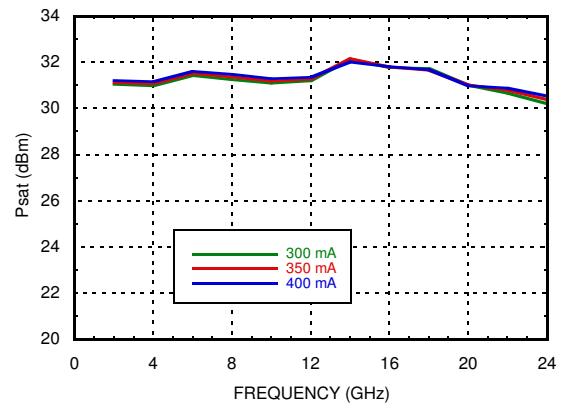
**Psat vs. Temperature**



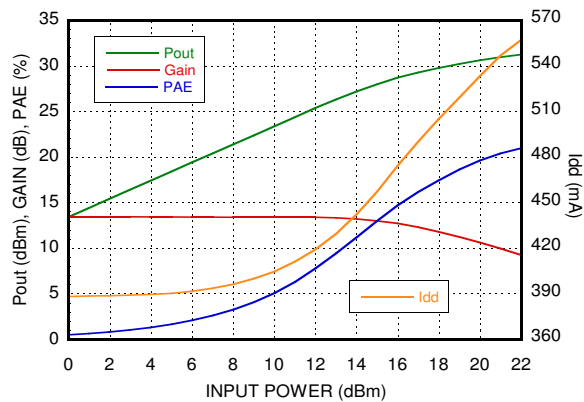
**Psat vs. Vdd**



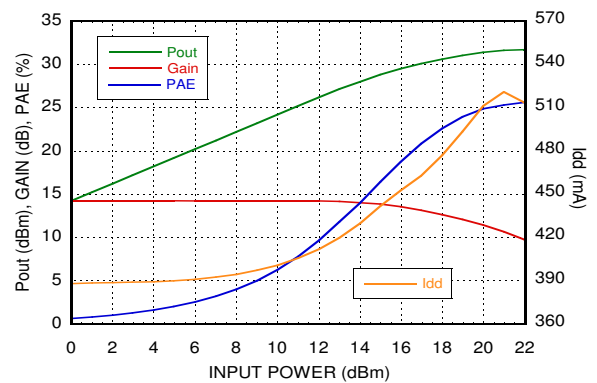
**Psat vs. Idd**



**Power Compression @ 2 GHz**

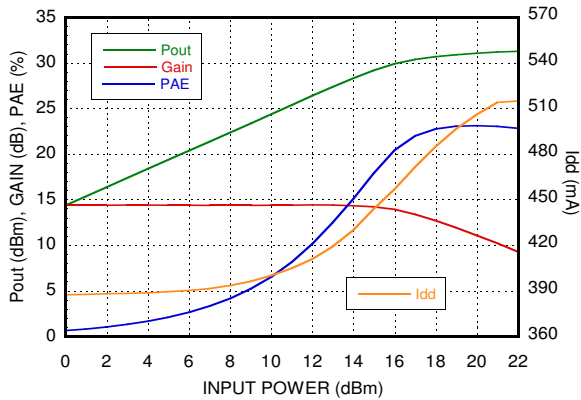


**Power Compression @ 6 GHz**

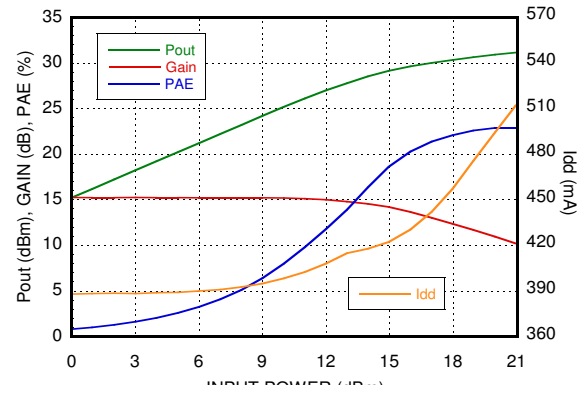


**GaAs pHEMT MMIC  
1 WATT POWER AMPLIFIER, DC - 22 GHz**

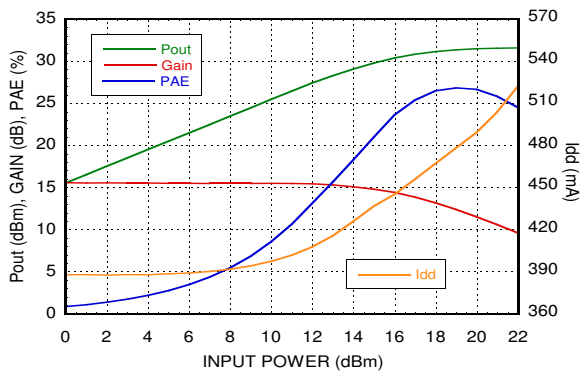
**Power Compression @ 10 GHz**



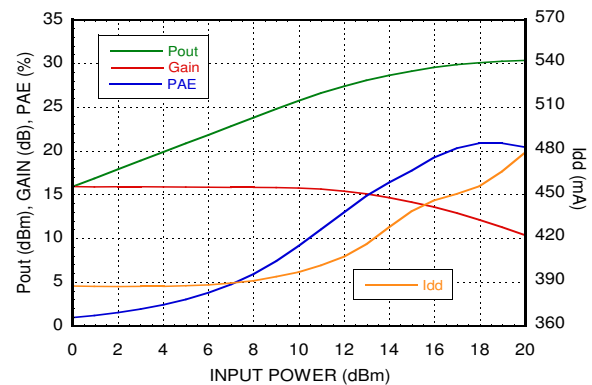
**Power Compression @ 14 GHz**



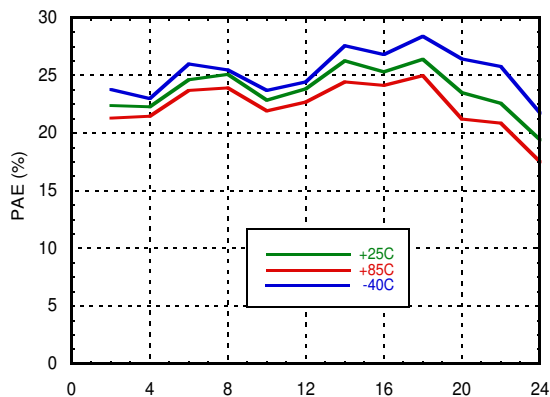
**Power Compression @ 18 GHz**



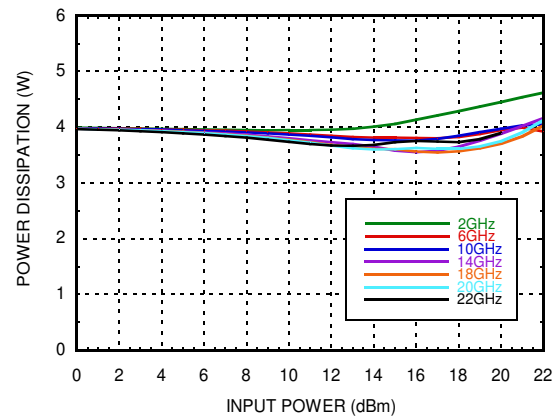
**Power Compression @ 22 GHz**



**PAE @ Psat vs. Frequency**

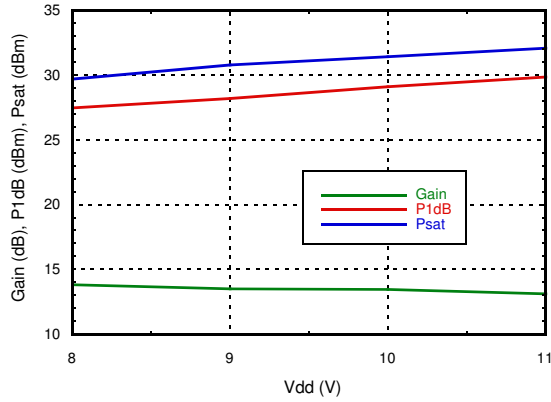


**Power Dissipation @ 85 C**

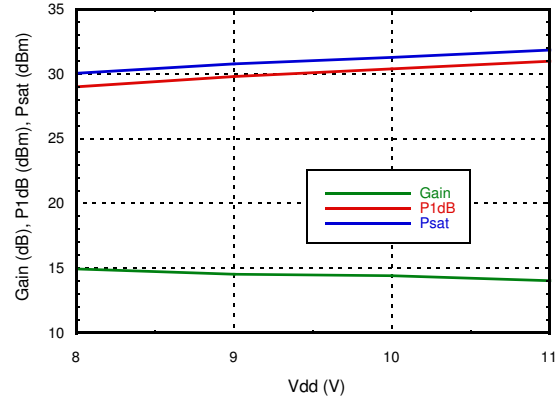


**GaAs pHEMT MMIC  
1 WATT POWER AMPLIFIER, DC - 22 GHz**

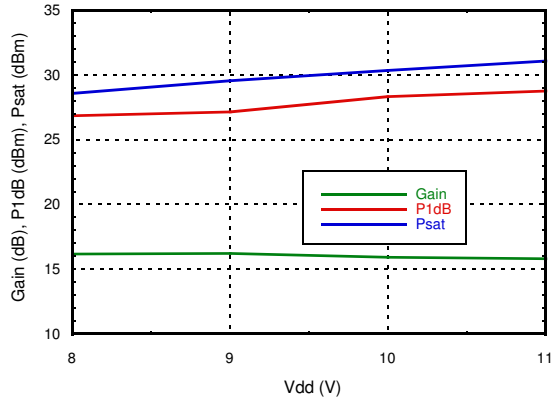
**Gain & Power vs. Vdd @ 2 GHz**



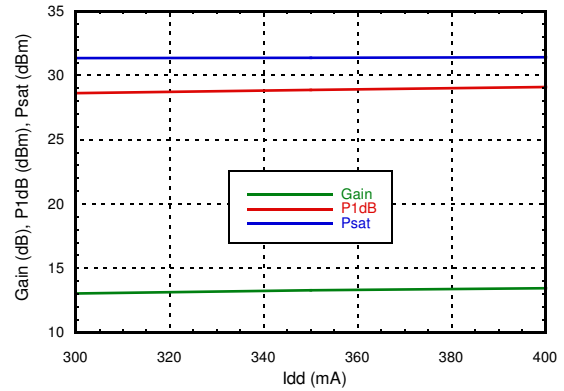
**Gain & Power vs. Vdd @ 10 GHz**



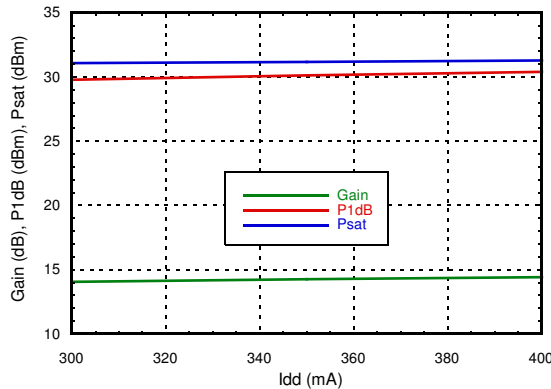
**Gain & Power vs. Vdd @ 22 GHz**



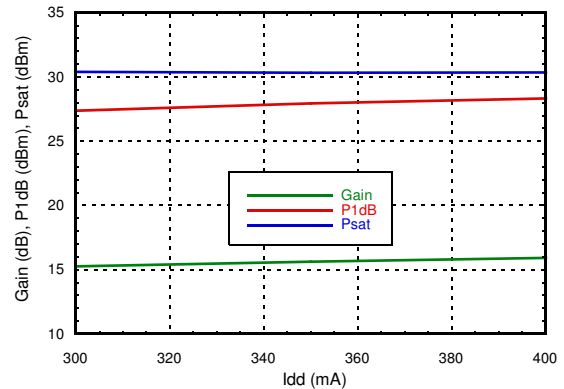
**Gain & Power vs. Idd @ 2 GHz**



**Gain & Power vs. Idd @ 10 GHz**

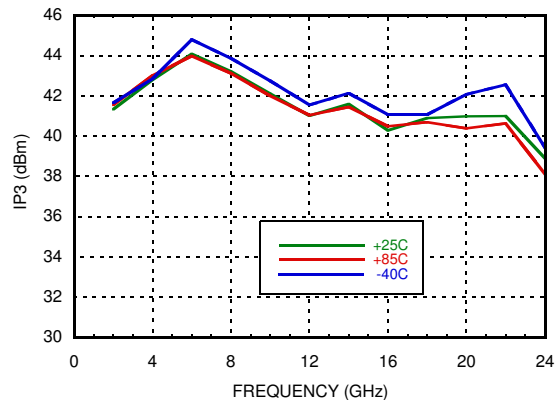


**Gain & Power vs. Idd @ 22 GHz**

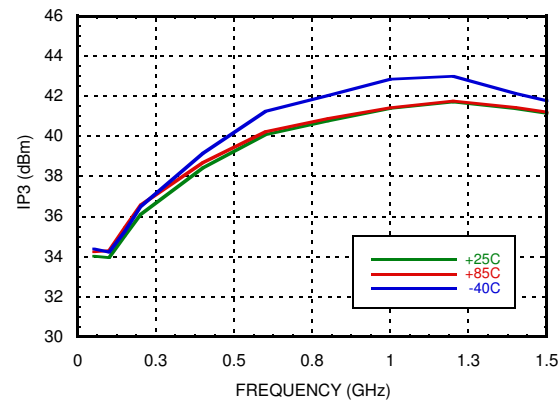


**GaAs pHEMT MMIC  
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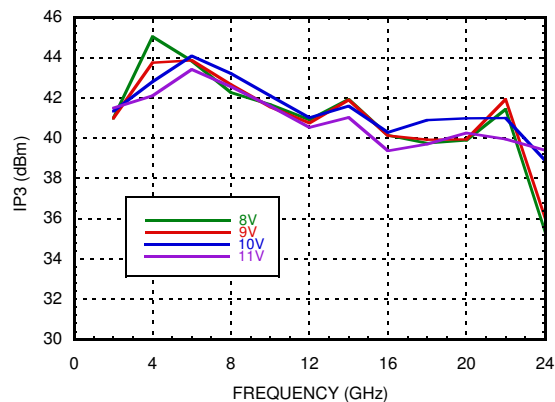
**OIP3 vs. Temperature**  
@ Pout / Tone = +18 dBm



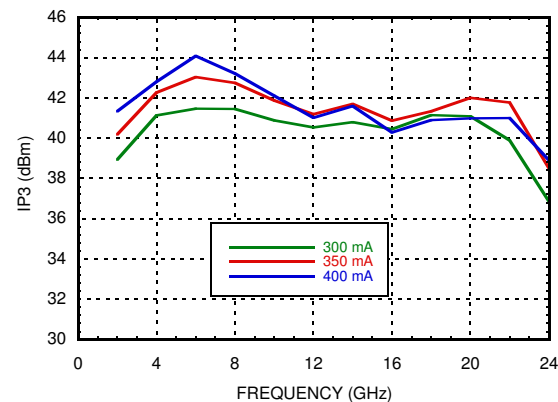
**Low Frequency OIP3 vs. Temperature**  
@ Pout / Tone = +18 dBm



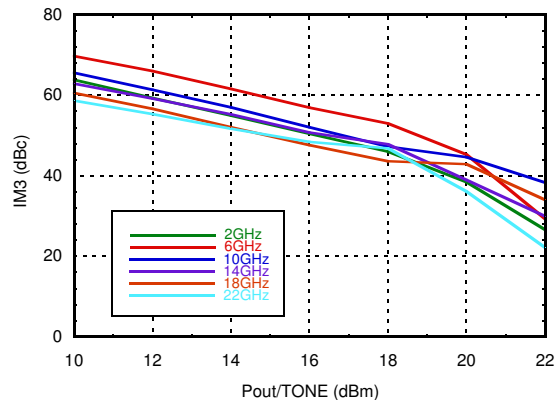
**OIP3 vs. Vdd**  
@ Pout / Tone = +18 dBm



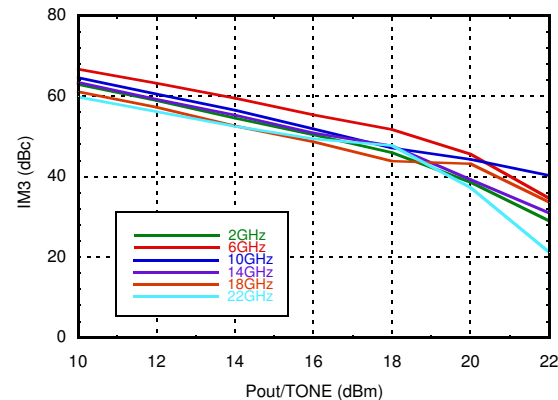
**OIP3 vs. Idd**  
@ Pout / Tone = +18 dBm



**Output IM3 @ Vdd = +8 V**



**Output IM3 @ Vdd = +9 V**

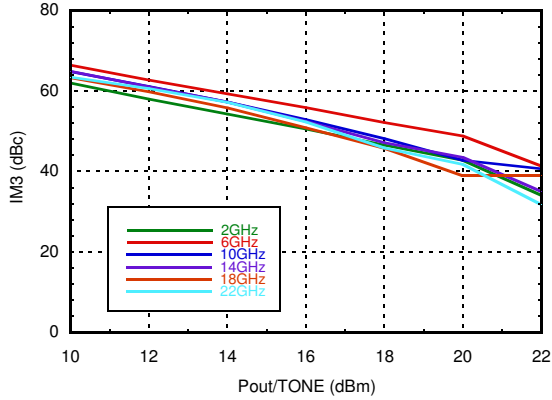




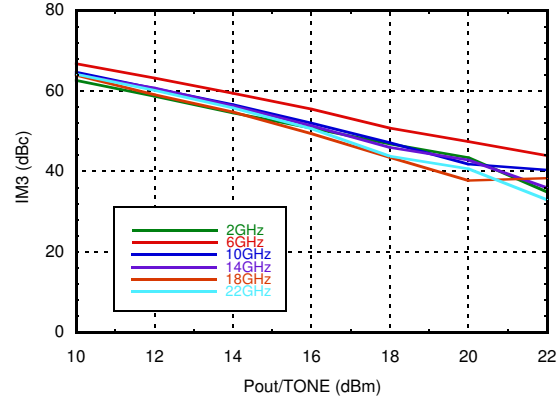
**GaAs pHEMT MMIC  
1 WATT POWER AMPLIFIER, DC - 22 GHz**

1AMPLIFIERS - LINEAR & POWER - SMT

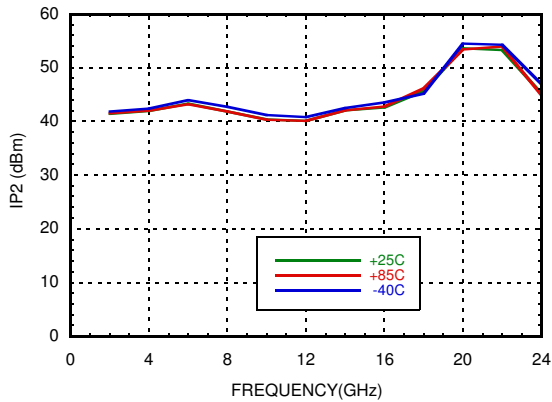
**Output IM3 @ Vdd = +10 V**



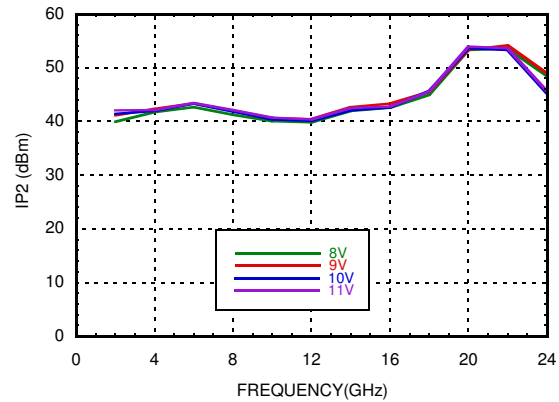
**Output IM3 @ Vdd = +11 V**



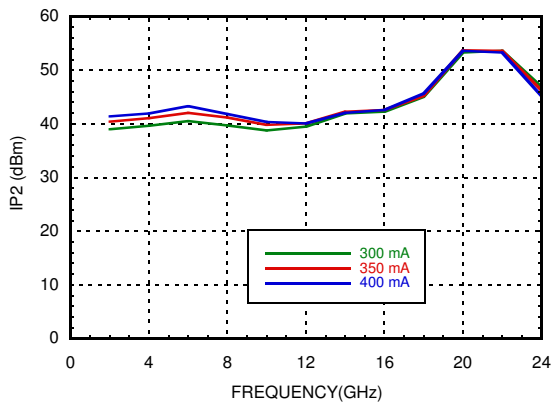
**OIP2 vs. Temperature  
@ Pout / Tone = +18 dBm**



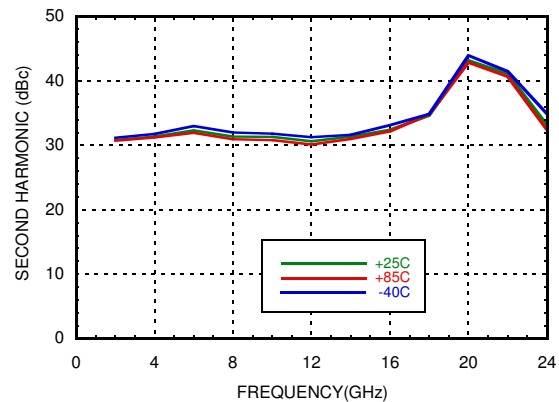
**OIP2 vs. Vdd  
@ Pout / Tone = +18 dBm**



**OIP2 vs. Idd  
@ Pout / Tone = +18 dBm**

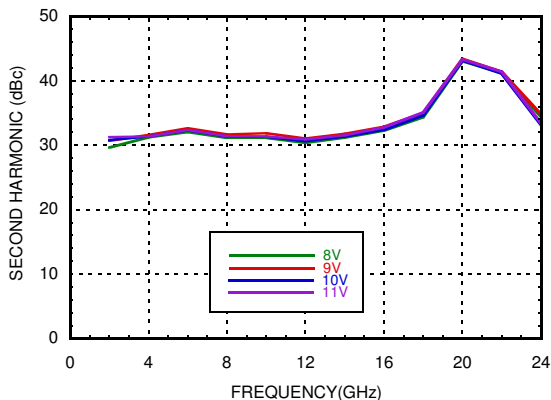


**Second Harmonics vs. Temperature  
@ Pout = +18 dBm**

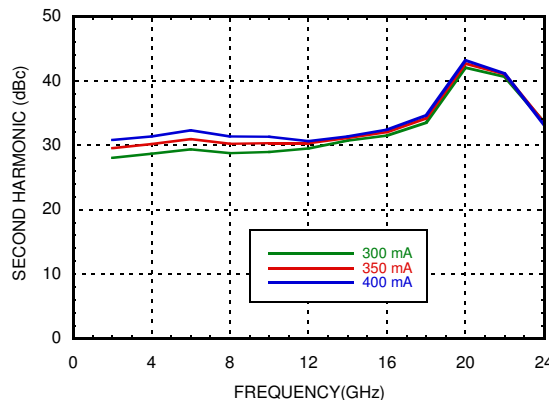


**GaAs pHEMT MMIC  
1 WATT POWER AMPLIFIER, DC - 22 GHz**

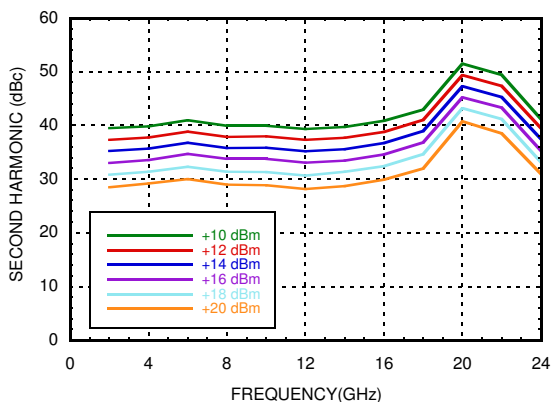
**Second Harmonics vs. Vdd  
@ Pout = +18 dBm**



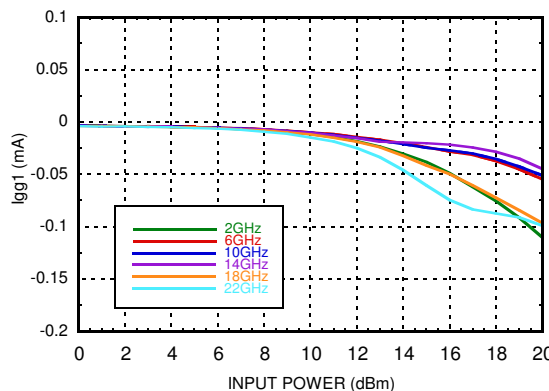
**Second Harmonics vs. Idd  
@ Pout = +18 dBm**



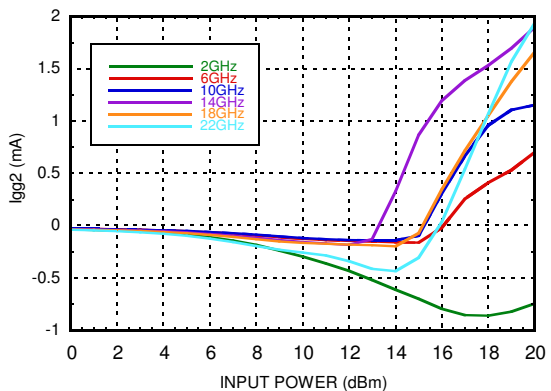
**Second Harmonics vs. Pout**



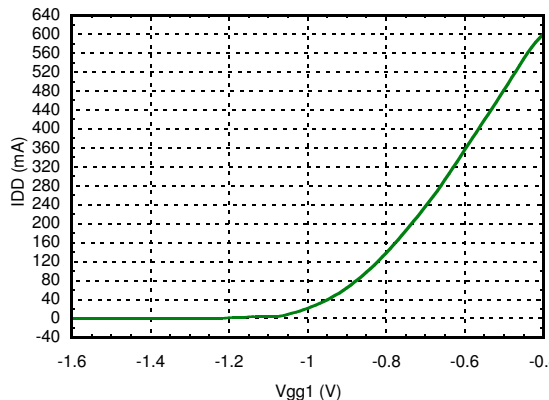
**Igg1 vs. Input Power**



**Igg2 vs. Input Power**




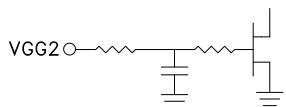
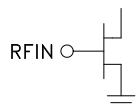
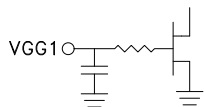
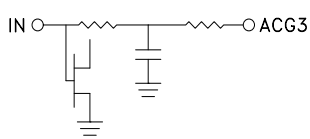
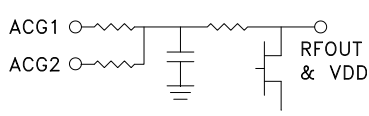
**Idd vs. Vgg1,  
Representative of a Typical Device**





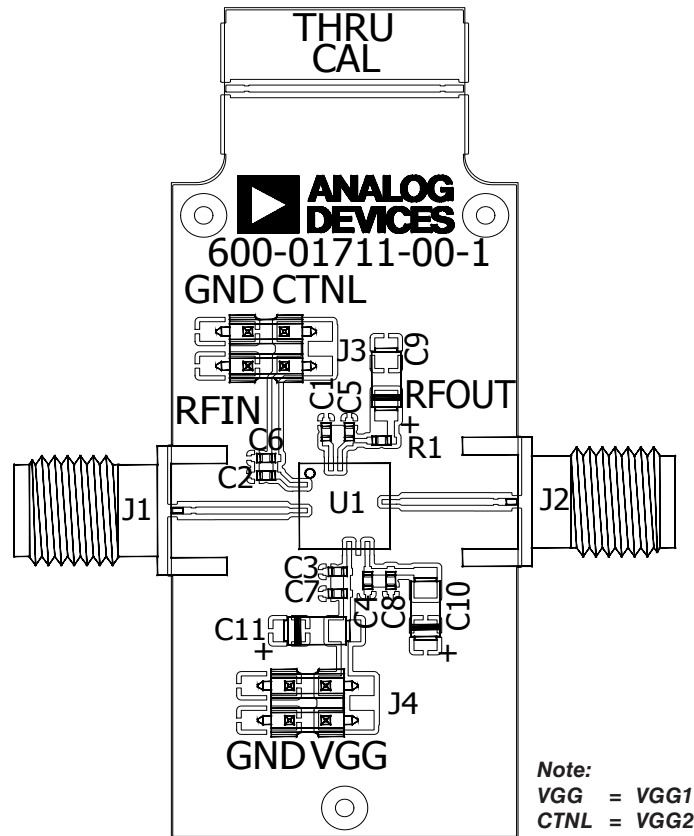
## GaAs pHEMT MMIC 1 WATT POWER AMPLIFIER, DC - 22 GHz

### Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 4, 6, 8, 9, 16, 17, 20, 22, 24, 25, 32 Package Bottom	GND	These pins & exposed ground paddle must be connected to RF/DC ground.	
2	VGG2	Gate control 2 for amplifier. Attach bypass capacitor per application circuit herein. For nominal operation +3.5V should be applied to Vgg2.	
3, 7, 10 - 12, 14, 18, 19, 23, 26 - 28, 31	N/C	No connection required. These pins may be connected to RF/DC ground without affecting performance.	
5	RFIN	This pad is DC coupled and matched to 50 Ohms. Blocking capacitor is required.	
13	VGG1	Gate control 1 for amplifier. Attach bypass capacitor per application circuit herein. Please follow "MMIC Amplifier Biasing Procedure" application note.	
15	ACG3	Low frequency termination. Attach bypass capacitor per application circuit herein.	
21	RFOUT & VDD	RF output for amplifier. Connect DC bias (Vdd) network to provide drain current (Idd). See application circuit herein.	
29	ACG2	Low frequency termination. Attach bypass capacitor per application circuit herein.	
30	ACG1		

## GaAs pHEMT MMIC 1 WATT POWER AMPLIFIER, DC - 22 GHz

### Evaluation PCB



### Evaluation Order Information

Item	Contents	Part Number
Evaluation PCB only	HMC797APM5E Evaluation PCB	EV1HMC797APM5

### List of Materials for Evaluation Board

Item	Description
J1, J2	SMA Connectors
J3, J4	DC Pins
C1 - C4	100 pF Capacitor, 0402 Pkg.
C5, C8	10 kpF Capacitor, 0402 Pkg.
C9 - C11	4.7 μF Capacitor, Tantalum
R1, R2	0 OHM Resistor, 0402 Pkg
U1	HMC797APM5E Power Amplifier
PCB [1]	600-01711-00 Evaluation PCB

[1] Circuit Board Material: Rogers 4350 or Arlon FR4

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Analog Devices, Inc.



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[MMZ25332B4T1](#) [SMA1212](#) [MAAMSS0041TR](#) [MAAM37000-A1G](#) [SMA88-1](#) [SMA4011](#) [A231](#) [UA5M20MC](#) [XD1001-BD-000V](#)  
[BGU6009/N2X](#) [BGS8H2X](#) [BGS8324Z](#) [SMA66](#) [A12](#) [MMA022AA](#) [MAAP-015024-DIE](#) [AMS-162-PIN](#) [CA70-2](#) [MMG30301BT1](#) [LA17](#)  
[MMA041PP5](#) [MAMF-011119-TR1000](#) [A57](#) [GRF2011](#) [MMA044PP3](#) [ISL55007IEZ-T7](#) [ISL55008IEZ-T7](#) [ISL55009IEZ-T7](#) [ISL55010IEZ-](#)  
[T7](#) [ISL55011IEZ-T7](#) [NSVG3117SG6T1G](#) [BGA7H1BN6E6327](#) [BGA125N6E6327XTSA1](#) [TRF1305B2RYPR](#) [TRF1208RPVT](#)  
[HMC797APM5ETR-R5](#) [HMC565LC5TR-R5](#) [HMC8413LP2FE](#)